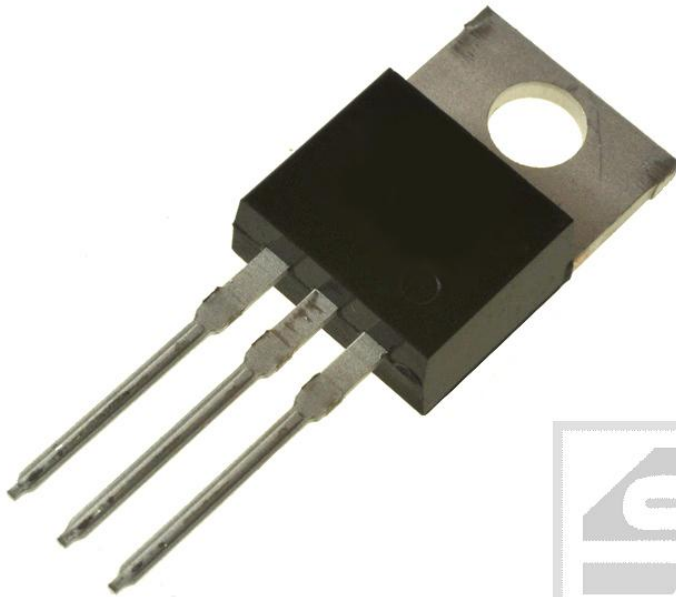




Dioda Schottky MBR1545CTG(duodiada) 15A 45V DO-220/3 ON-Semiconductor RoHS



Dane techniczne:

Nazwa: MBR1545CTG

Typ diody: prostownicza Schottky

Napięcie wsteczne maksymalne: 45V

Napięcie przewodzenia maksymalne: 0.72V

Prąd przewodzenia diody: 2x7.5A

Prąd przewodzenia maksymalny: 15A

Prąd w impulsie maksymalny: 150A

Struktura półprzewodnika: podwójna, wspólna katoda

Obudowa: DO-220/3

Montaż: przewlekany(THT)

Producent: ON-Semiconductor

www.podzespoly-elektroniczne.pl

MBR1535CT, MBR1545CT

MBR1545CT is a Preferred Device

SWITCHMODE™ Power Rectifier

... using the Schottky Barrier principle with a platinum barrier metal. These state-of-the-art devices have the following features:

- Center-Tap Configuration
- Guardring for Stress Protection
- Low Forward Voltage
- 150°C Operating Junction Temperature
- Epoxy Meets UL94, VO at 1/8"

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 units per plastic tube
- Marking: B1535, B1545

MAXIMUM RATINGS

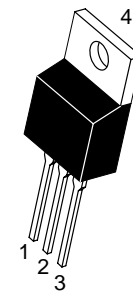
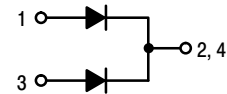
Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	35 45	V
Average Rectified Forward Current (Rated V_R , $T_C = 105^\circ\text{C}$) Per Diode Per Device	$I_{F(AV)}$	7.5 15	A
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz, $T_C = 105^\circ\text{C}$) Per Diode	I_{FRM}	15	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I_{FSM}	150	A
Peak Repetitive Reverse Surge Current (2.0 μs , 1.0 kHz)	I_{RRM}	1.0	A
Storage Temperature Range	T_{stg}	-65 to +175	°C
Operating Junction Temperature	T_J	-65 to +150	°C
Voltage Rate of Change (Rated V_R)	dv/dt	1000	V/ μs



ON Semiconductor™

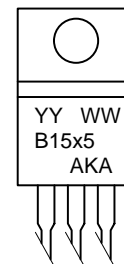
<http://onsemi.com>

SCHOTTKY BARRIER RECTIFIERS 15 AMPERES 35 and 45 VOLTS



TO-220AB
CASE 221A
PLASTIC

MARKING DIAGRAM



YY = Year
WW = Work Week
B15x5 = Device Code
x = 3 or 4
AKA = Diode Polarity

ORDERING INFORMATION

Device	Package	Shipping
MBR1535CT	TO-220	50 Units/Rail
MBR1545CT	TO-220	50 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

MBR1535CT, MBR1545CT

THERMAL CHARACTERISTICS PER DIODE

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance, Junction to Case	$R_{\theta JC}$	3.0	$^{\circ}\text{C}/\text{W}$
Maximum Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	60	$^{\circ}\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS PER DIODE

Maximum Instantaneous Forward Voltage (Note 1.) ($i_F = 7.5$ Amps, $T_C = 125^{\circ}\text{C}$) ($i_F = 15$ Amps, $T_C = 125^{\circ}\text{C}$) ($i_F = 15$ Amps, $T_C = 25^{\circ}\text{C}$)	V_F	0.57 0.72 0.84	Volts
Maximum Instantaneous Reverse Current (Note 1.) (Rated dc Voltage, $T_C = 125^{\circ}\text{C}$) (Rated dc Voltage, $T_C = 25^{\circ}\text{C}$)	i_R	15 0.1	mA

1. Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$

MBR1535CT, MBR1545CT

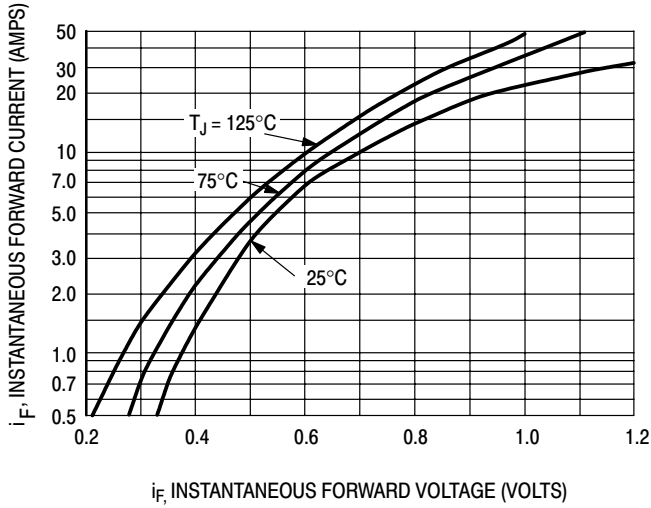


Figure 1. Typical Forward Voltage

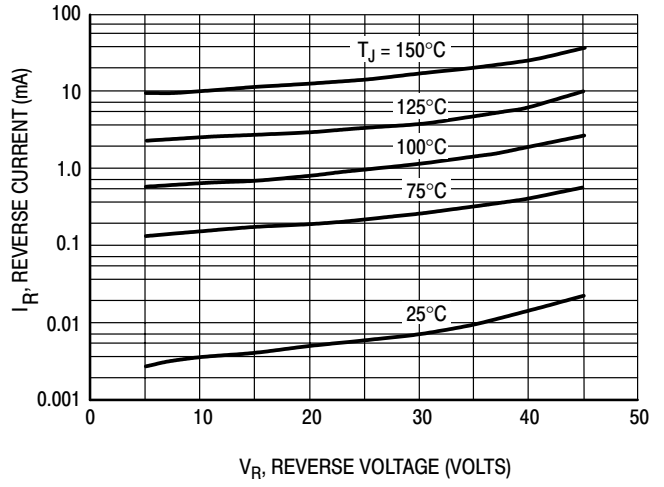


Figure 2. Typical Reverse Current

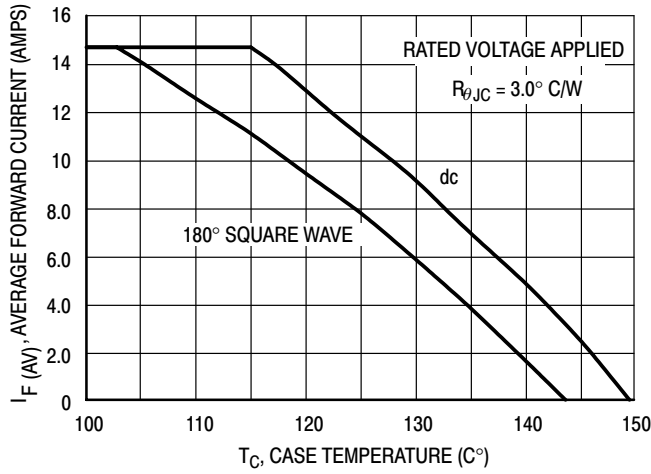


Figure 3. Current Derating, Case

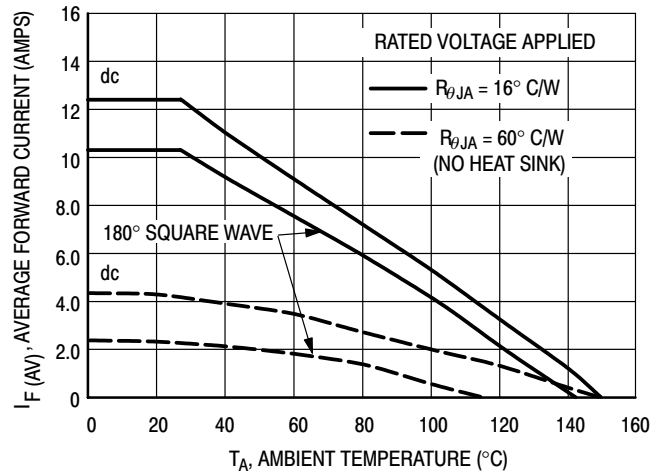


Figure 4. Current Derating, Ambient

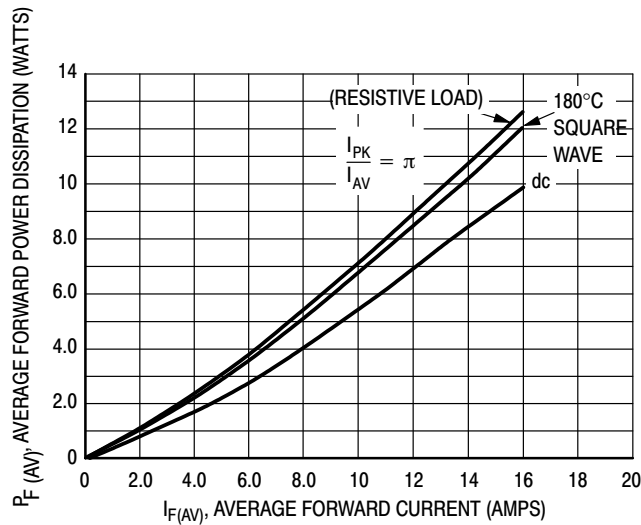
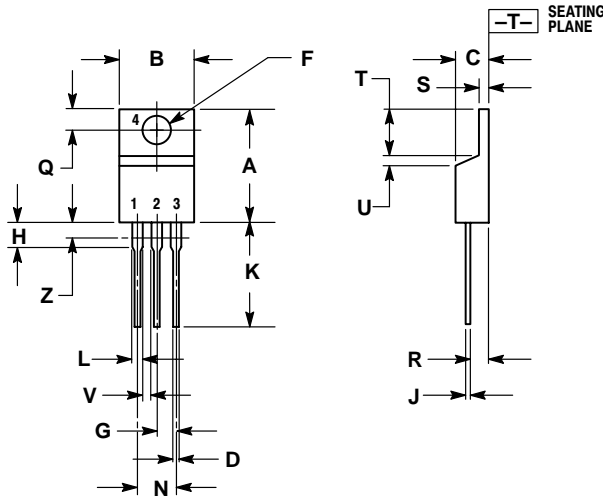


Figure 5. Power Dissipation

MBR1535CT, MBR1545CT

PACKAGE DIMENSIONS

TO-220 THREE LEAD
TO-220AB
CASE 221A-09
ISSUE AA




NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

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